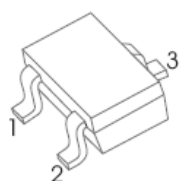


Features

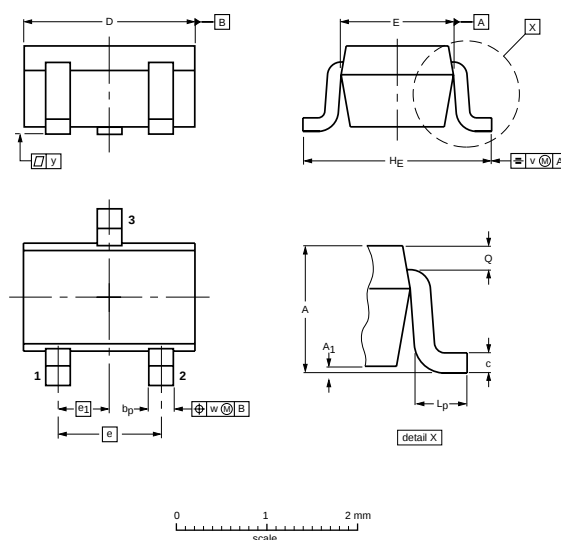
for switching and amplifier applications



SOT-323

1. BASE
2. EMITTER
3. COLLECTOR

SOT-323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

Absolute Maximum Ratings (T_a = 25 °C)

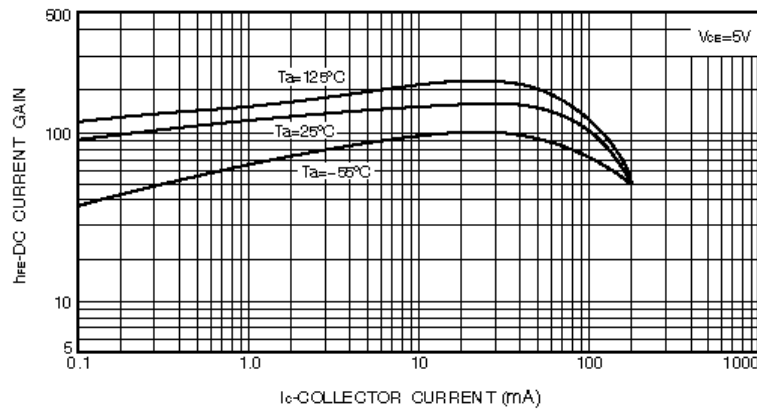
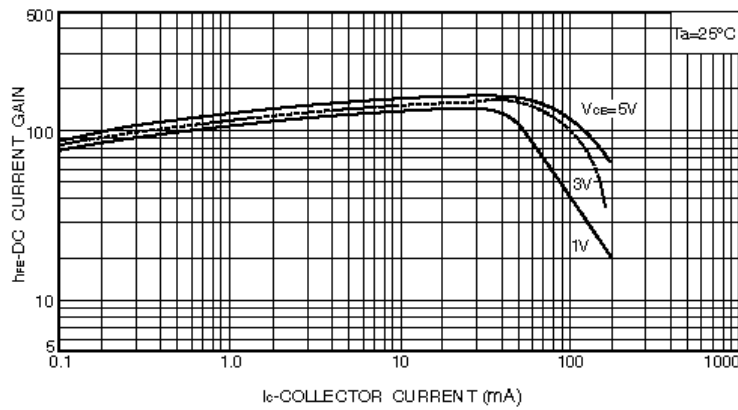
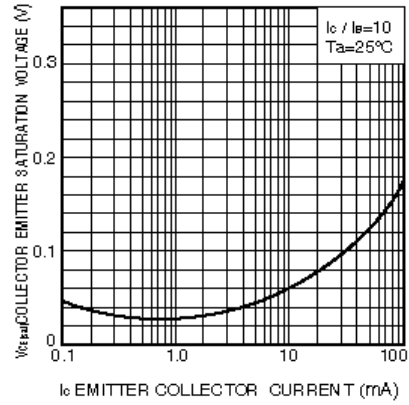
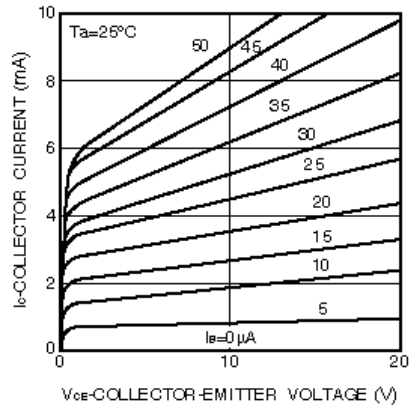
Parameter	Symbol	Value	Unit
Collector Base Voltage	-V _{CBO}	40	V
Collector Emitter Voltage	-V _{CEO}	40	V
Emitter Base Voltage	-V _{EBO}	5	V
Collector Current	-I _C	200	mA
Total Power Dissipation	P _{tot}	200	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	- 55 to +150	°C

MMBT3906W

Characteristics at $T_a = 25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $-V_{CE} = 1\text{ V}$, $-I_C = 1\text{ mA}$ at $-V_{CE} = 1\text{ V}$, $-I_C = 10\text{ mA}$ at $-V_{CE} = 1\text{ V}$, $-I_C = 50\text{ mA}$ at $-V_{CE} = 1\text{ V}$, $-I_C = 100\text{ mA}$	h_{FE}	80 100 60 30	- 300 - -	- - - -
Collector Emitter Cutoff Current at $-V_{CE} = 30\text{ V}$	$-I_{CES}$	-	50	nA
Emitter Base Cutoff Current at $-V_{EB} = 3\text{ V}$	$-I_{EBO}$	-	50	nA
Collector Base Breakdown Voltage at $-I_C = 10\text{ }\mu\text{A}$	$-V_{(BR)CBO}$	40	-	V
Collector Emitter Breakdown Voltage at $-I_C = 1\text{ mA}$	$-V_{(BR)CEO}$	40	-	V
Emitter Base Breakdown Voltage at $-I_E = 10\text{ }\mu\text{A}$	$-V_{(BR)EBO}$	5	-	V
Collector Emitter Saturation Voltage at $-I_C = 10\text{ mA}$, $-I_B = 1\text{ mA}$ at $-I_C = 50\text{ mA}$, $-I_B = 5\text{ mA}$	$-V_{CE(sat)}$	- -	0.25 0.4	V
Base Emitter Saturation Voltage at $-I_C = 10\text{ mA}$, $-I_B = 1\text{ mA}$ at $-I_C = 50\text{ mA}$, $-I_B = 5\text{ mA}$	$-V_{BE(sat)}$	0.65 -	0.85 0.95	V
Transition Frequency at $-V_{CE} = 20\text{ V}$, $I_E = 10\text{ mA}$, $f = 100\text{ MHz}$	f_T	250	-	MHz
Collector Output Capacitance at $-V_{CB} = 10\text{ V}$, $f = 100\text{ KHz}$	C_{ob}	-	4.5	pF
Delay Time at $-V_{CC} = 3\text{ V}$, $-V_{BE(OFF)} = 0.5\text{ V}$, $-I_C = 10\text{ mA}$, $-I_{B1} = 1\text{ mA}$	t_d	-	35	ns
Rise Time at $-V_{CC} = 3\text{ V}$, $-V_{BE(OFF)} = 0.5\text{ V}$, $-I_C = 10\text{ mA}$, $-I_{B1} = 1\text{ mA}$	t_r	-	35	ns
Storage Time at $-V_{CC} = 3\text{ V}$, $-I_C = 10\text{ mA}$, $I_{B1} = -I_{B2} = -1\text{ mA}$	t_{stg}	-	225	ns
Fall Time at $-V_{CC} = 3\text{ V}$, $-I_C = 10\text{ mA}$, $I_{B1} = -I_{B2} = -1\text{ mA}$	t_f	-	75	ns

RATING AND CHARACTERISTIC CURVES (MMBT3906W)



RATING AND CHARACTERISTIC CURVES (MMBT3906W)

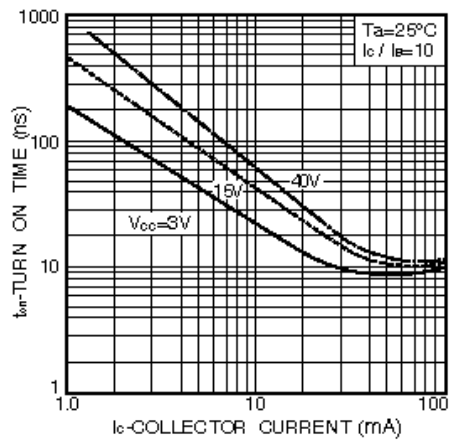


Fig.8 Turn-on time vs. collector current

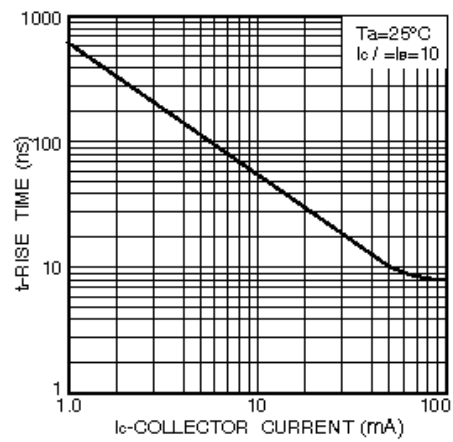


Fig.9 Rise time vs. collector current

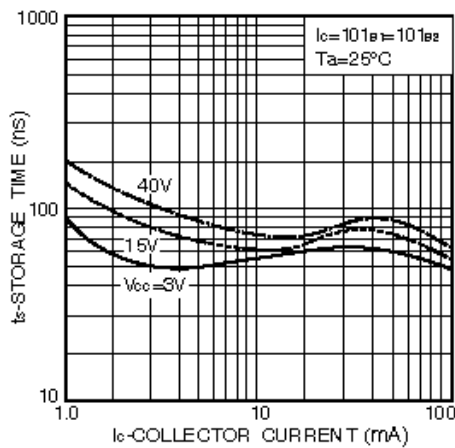


Fig.10 Storage time vs. collector current

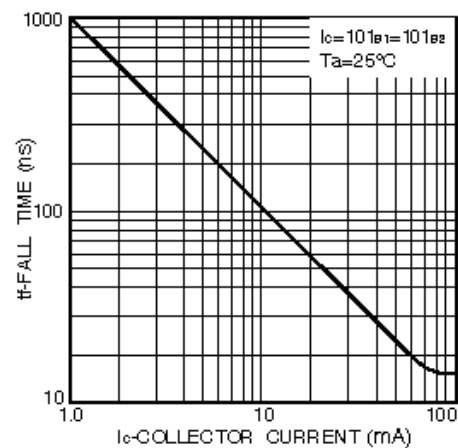


Fig.11 Fall time vs. collector current

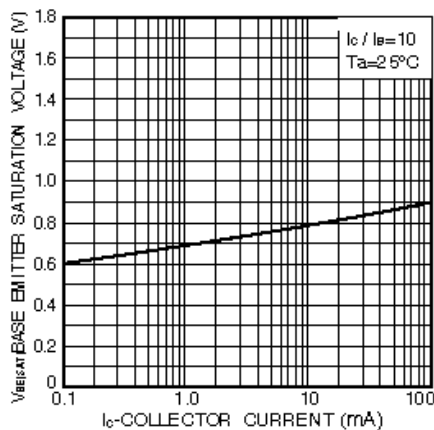


Fig.6 Base-emitter saturation voltage vs. collector current

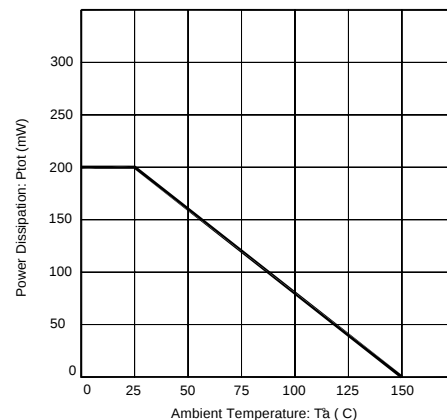


Fig.10 Power Dissipation vs Ambient Temperature